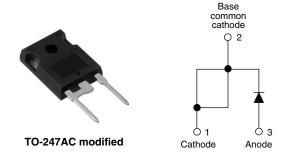


## Vishay High Power Products

# Hyperfast Rectifier, 30 A FRED Pt<sup>TM</sup>



# PRODUCT SUMMARY t<sub>rr</sub> (typical) 28 ns I<sub>F(AV)</sub> 30 A V<sub>R</sub> 600 V

#### **FEATURES**

- Hyperfast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- · Single diode device
- Designed and qualified for industrial level

#### **DESCRIPTION/APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC-DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	$V_{RRM}$		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 116 °C	30	Δ.		
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	300	Α		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	2.0	2.6	
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	=	1.34	1.75	
Reverse leakage current		V <sub>R</sub> = V <sub>R</sub> rated	-	0.3	50	μΑ
	I <sub>R</sub>	T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	=	60	500	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	=	33	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body -		3.5	-	nH

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## 30EPH06

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, dI_F/dt =$	= 50 A/μs, V <sub>R</sub> = 30 V	-	28	35	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	31	-	ns
		T <sub>J</sub> = 125 °C		=	77	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	3.5	-	Α
		T <sub>J</sub> = 125 °C		=	7.7	-	
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		=	65	-	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	345	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	0.5	0.9	
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount -		-	70	°C/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.4	-	
Weight			-	6.0	-	g
			-	0.22	-	OZ.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC modified	30EPH06		•	

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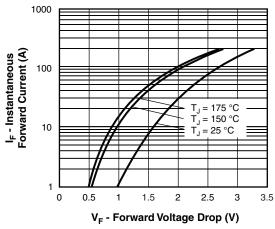


Fig. 1 - Typical Forward Voltage Drop Characteristics

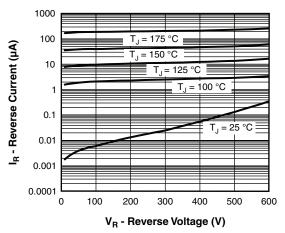


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

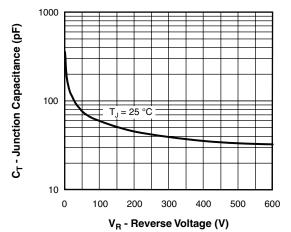


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

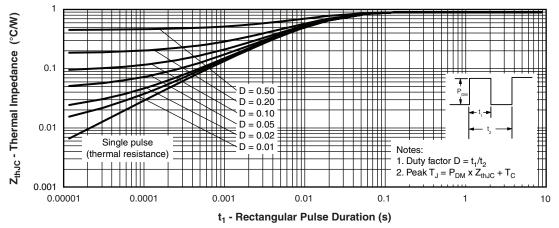


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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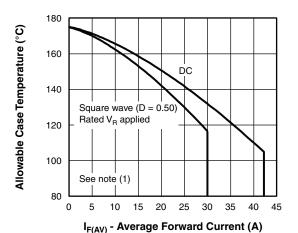
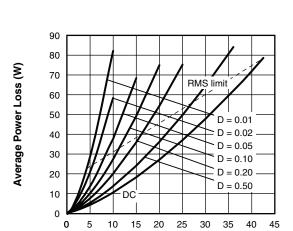


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current



I<sub>F(AV)</sub> - Average Forward Current (A)
Fig. 6 - Forward Power Loss Characteristics

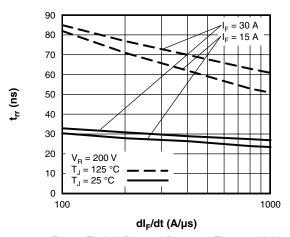


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

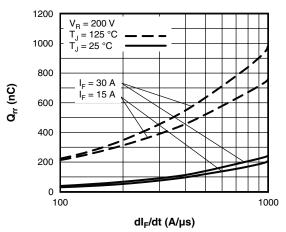


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \text{(1)} \;\; \text{Formula used:} \; T_C = T_J - (Pd + Pd_{REV}) \; x \; R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \; x \; V_{FM} \; \text{at} \; (I_{F(AV)}/D) \; (\text{see fig. 6}); \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \; x \; I_R \; (1 - D); \; I_R \; \text{at} \; V_{R1} = \text{Rated} \; V_R \\ \end{array}$ 



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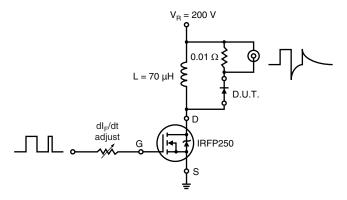
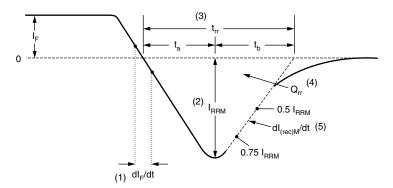


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $\rm I_{RRM}$  peak reverse recovery current
- (3)  $t_{\rm rr}$  reverse recovery time measured from zero crossing point of negative going  $I_{\rm F}$  to point where a line passing through 0.75  $I_{\rm RRM}$  and 0.50  $I_{\rm RRM}$  extrapolated to zero current.
- (4)  $\rm Q_{rr}$  area under curve defined by  $\rm t_{rr}$  and  $\rm I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

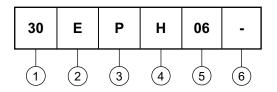
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#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Current rating (30 = 30A)

2 - Circuit configuration:

E = Single diode

3 - Package:

P = TO-247AC modified

- H = Hyperfast recovery

5 - Voltage rating (06 = 600V)

None = Standard production

• PbF = Lead (Pb)-free

Tube standard pack quantity: 25 pieces

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95253			
Part marking information	http://www.vishay.com/doc?95255			

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